

## **Data Sheet**

### iMOTION™ Motion Controller Module for PM AC Fan

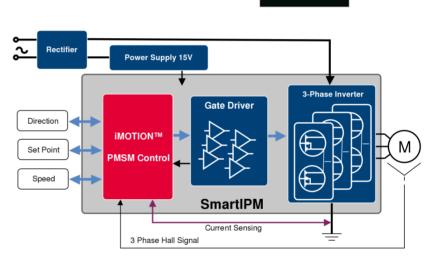
## **Quality Requirement Category: Industry**

#### **Features**

- Complete 250V 500V 3-phase inverter system in one chip
- Permanent Magnet Sinusoidal Motors Control by Hall sensors
- High efficiency control by quadratic phase advance curve
- Internal clock based on external RC
- 15V single power supply3.3V Integrated Voltage Regulator
- Integrated protection features:
   Dynamic overcurrent, Overtemperature,
   Overspeed, Rotor lock, Undervoltage lockout
- Full Three Phase Gate Driver
- Integrated Bootstrap Diodes
- No heatsink required
- 12x12 mm<sup>2</sup> PQFN package

## **Applications**

PM fan motor control



## Description

IRDM982-025MB, IRDM982-035MB are the complete PM motor controller including six power MOSFET, high voltage integrated circuit, high precision analog circuit and integrated digital control algorithm. The controller implements a Hall sensor based control algorithm for 3-phase sinusoidal permanent magnet motor fan applications.

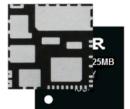
The integrated digital controller does not require any programming.

Instead there are 16 load curves stored in the internal ROM that can be selected via two resistor pairs.

The IRDM982 is packaged in the 12 x 12 PQFN package and designed to dissipate the power loss through a PCB without the use of an external heatsink.

There are two products available depending on the power rating of the internal high voltage MOSFETs:

- 1) IRDM982-025MB employs six MOSFETs 500V 2A and 600V high voltage IC
- 2) IRDM982-035MB employs six MOSFETs 500V 3A and 600V high voltage IC





### IRDM982 Series - IRDM982-025MB, IRDM982-035MB **Complete Motion Controller Module for PM AC fan**

#### **Features**

- Complete 250V 500V 3-phase inverter system in one
- No heatsink required
- Permanent Magnet Sinusoidal Motors Control by Hall sensors
- Selectable 4 or 12 pulse output per revolution<sup>1)</sup>
- High efficiency control by quadratic phase advance curve
- Internal clock based on external RC
- 15V single power supply
- 3.3V Integrated Voltage Regulator
- Dynamic overcurrent limit per temperature
- Overtemperature control
- Overspeed protection
- Rotor lock detection/protection
- Full Three Phase Gate Driver
- Integrated Bootstrap Diodes
- Undervoltage lockout

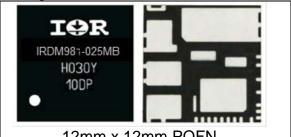
#### **Typical Applications**

Fan motor control

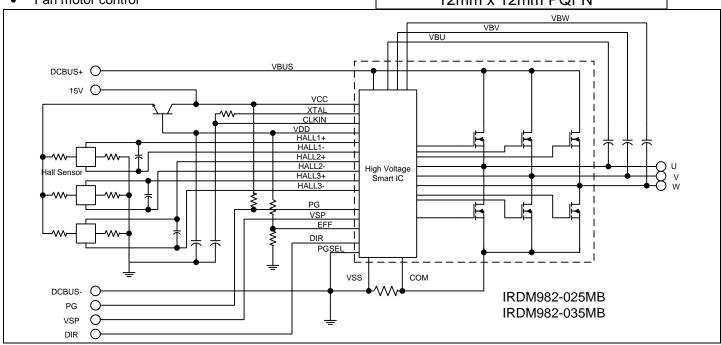
#### **Product Summary**

Topology	3 Phase AC
V <sub>OFFSET</sub>	≤ 500 V for IRDM982-025MB, IRDM982-035MB
Control	Phase Advancement control
Feedback	DC Bus shunt, 3 Hall sensor
Temperature sensor	Integrated

#### **Package**



12mm x 12mm PQFN



1) When used with 8 poles motor. In general it is 1 pulse / 3 pulses per electrical revolution.



Table of Contents
INTRODUCTION3
QUALIFICATION INFORMATION5
IRDM982-025MB / IRDM982-035MB ELECTRICAL CHARACTERISTICS9
LEAD DEFINITIONS21
PACKAGE OUTLINE23
PACKAGE MARKING25
SOLDERING TEMPERATURE PROFILE26



#### Introduction

IRDM982-025MB, IRDM982-035MB are the complete PM motor controller including six power MOSFET, high voltage integrated circuit, high precision analog circuit and digital control algorithm. There are three products depending on power rating of internal high voltage MOSFET listed below:

- 1) IRDM982-025MB employs six MOSFET 500V 2A and 600V high voltage IC
- 2) IRDM982-035MB employs six MOSFET 500V 3A and 600V high voltage IC

All two products are packaged in the 12 x 12 PQFN package and designed to dissipate the power loss through a mating PCB without an external heatsink. All two products contain exactly same control algorithm and analog functions. The controller implements a Hall sensor based control algorithm for 3-phase sinusoidal permanent magnet motor fan applications. The control also employs high efficiency PM motor control algorithm based on a quadratic load curve stored in internal ROM. 16 possible curves are selectable.

All devices have an on-chip voltage regulator to derive the 3.3V, required by the digital logic, from the 15V (VCC) supply. The 3.3VDC regulated voltage pin is available externally for connection to Hall-effect sensors. The IC provides low power standby (less than 7mW) mode of operation that 3.3V power is cut off when VSP (Voltage Input) becomes less than 1.15V to provide further power efficient operation.

An integrated A/D Converter is used to acquire EFF load curve selection, temperature (internal temp sensing), and the VSP input that sets the voltage applied to the motor.

An internal temperature sensor is interfaced to the ADC and resulting digital conversion data is used to control the dynamic overcurrent setpoints as well as max overtemperature limit.

The protection functions include a supply under-voltage lockout (3.3V and 15VDC), over-speed protection, over-temperature limit and Over-current limitation protections. The reset circuitry includes a Power-On reset block and a reset input.

All devices do not require any programming. Default coefficients and system parameters are stored in internal ROM. The EFF input pin, used to adapt to specific motor and load to improve efficiency, can be used by means of two resistor pairs to choose one of 16 pre-stored load curves in ROM. DIR is a digital input pins which specify the motor direction command (CW or CCW).

All devices have an on-chip PLL to generate internal clocks. The PLL requires an external low frequency reference clock (32,768 Hz). The clock can be provided through an RC network connected to CLKIN and XTAL pins.

The IRDM982-025MB, IRDM982-035MB integrate high and low side gate drivers for applications up to 500V, it includes integrated Bootstrap FET that emulate bootstrap diode function and six power MOSFETs. The simplified block diagram is shown in Figure 1 in terms of hardware elements.



## Simplified Block Diagram

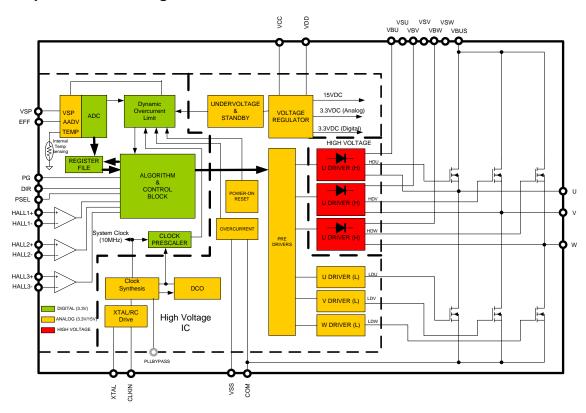


Figure 1 Simplified Block Diagram



## **Qualification Information**

Qualif	ication Level	Industrial <sup>††</sup> (per JEDEC JESD 47) Stress Test ; Preconditioning, Temp Cycle, Autoclave, THB, HTSL, LTSL, IOL,			
Moisture Sensitivity Level		PQFN	MSL3 <sup>†††</sup> (per IPC/JEDEC J-STD-020) Floor Life Time; 168 hours Conditions; <30°C/60% RH Bake conditions; 125 +5/-0°C, 24 hours minimum		
	Machine Model	Class B (per JEDEC Standard JESD22-A115) R1=00, C1=200pF+/-10% Any part that passes after exposure to an ESD pulse of 200V, but fails after exposure to an ESD pulse of 400V.			
ESD	Human Body Model	Class 2 (per EIA/JEDEC standard EIA/JESD22-A114) R1=15000+/-1%, C1=100pF+/-10% Any part that passes after exposure to an ESD pulse of 2000V, but fails after exposure to an ESD pulse of 4000V.			
	Charged Device Model Class IV (per JEDEC standard JESD22-C101 >1000V				
IC Lat	ch-Up Test	Class I, Level A (per JES Testing performed at roor The failure criteria as defi	n temperature ambient.		
RoHS	Compliant	Yes			

<sup>†</sup> Qualification standards can be found at International Rectifier's web site <a href="http://www.irf.com/">http://www.irf.com/</a>

<sup>††</sup> Higher qualification ratings may be available should the user have such requirements. Please contact your International Rectifier sales representative for further information.

<sup>†††</sup> Higher MSL ratings may be available for the specific package types listed here. Please contact your International Rectifier sales representative for further information.



CLASS	TEST TYPE	TRICCER POLARITY	CONDITION OF UNIESTED INPUT PINS	TEST TEMPERATURE (±2°C)	V <sub>supply</sub> CONDITION	TRIGGER TEST CONDITIONS [6]	FAILURE CRITERIA								
		POSITIVE see FIGURE	Max. Logic High [1] Min. Logic Low [1]			+(Inom+ 100 mA) or 1.5X Inom, whichever is greater [3]									
ı	I-TEST	NEGATIVE see FIGURE	Max, Logic High [1] Min, Logic Low [1]	Room temperature	Room fi temperature	Maximum operating voltage for each	-100 mA or5X Inom, whichever is greater in magnitude [4]								
	V <sub>supply</sub> OVER- VOLT-	see	Max. Logic High [1]			temperature	temperature	temperature	temperature	temperature	x. Logic pin group igh [1] per device		temperature	temperature	i suppry
	AGE TEST	FIGURE	Min. Logic Low [1]			V <sub>supply</sub> [2]	1.4X Inom or Inom +10 mA								
	. ———	POSITIVE see FIGURE	Max. Logic High [1] Min. Logic Low [1]	Maximum operating Maximum voltage					+(Inom+100 mA) or 1.5X Inom, whichever is greater [3]	whichever is greater [6]					
11	I-TEST	NEGATIVE see FIGURE	Max. Logic High [1] Min. Logic Low [1]		operating voltage	-100 mA or5 X Inom, whichever is greater in magnitude [4]									
	V <sub>supply</sub> OVER-	see	Max. Logic High [1]	ambient operating temperature	for each  V <sub>supply</sub> pin group  per device  specification	1.5 X max.									
	VOLT- AGE TEST	FIGURE	Min. Logic Low[1]	_		V <sub>supply</sub> [2]									

Table 1.



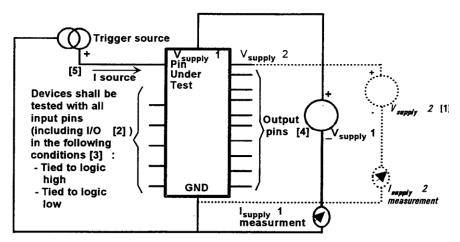
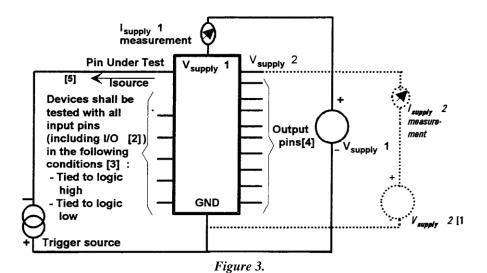


Figure 2.



i<sub>supply</sub> 1 measurement [5] V<sub>supply</sub> 2 V<sub>supply</sub> Devices shall be tested with all input pins (including I/O [2]) measure in the following Output тепт conditions [3] : pins[4]  $V_{\text{supply}}$ - Tied to logic high - Tied to logic low **GND** 2 [1] Figure 4.



#### IRDM982-025MB/-035MB Electrical Characteristics

#### Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to **VSS** unless otherwise stated in the table. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ta=25C, unless otherwise stated.

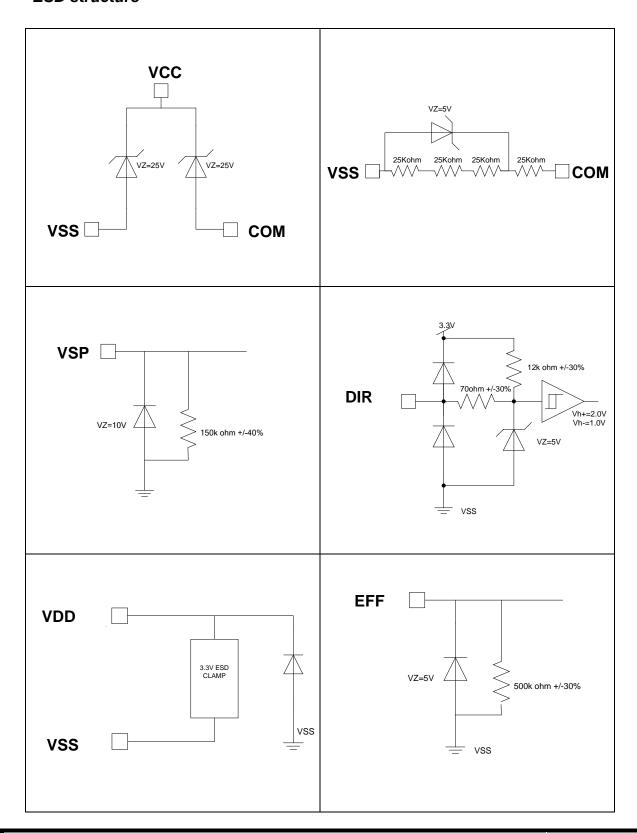
Symbol	Definition	Min.	Max.	Units	Condition
$V_{ISO}$	Isolation voltage	1500	-	Vrms	AC 1 minute
VISO	Isolation voltage	1800	-	VIIIIS	AC 1 second
BODIIO		500		IRDM982-025MB IRDM982-035MB	
DCBUS	DC bus voltage	-	630		IRDM982-025MB IRDM982-035MB 10usec <sup>1)</sup>
DCBUS <sub>STAT</sub>	DC bus voltage for PWM off 1)	-	900	V	IRDM982-025MB IRDM982-035MB VSP=0V, 1 minute, CO1=CO2 <sup>2)</sup>
VBU, VBV, VBW	High-side floating absolute voltage	-0.3	525		
VSU, VSV, VSW	High-side floating supply offset voltage	VB - 25	VB + 0.3		
VCC	Low side power supply absolute voltage	-0.3	24		
	Drain current, IRDM982-035MB	-	3.9		Tc=25°C, Rth=2C/W
	Drain current, IRDM982-025MB	-	2.6	Α	Tc=25°C, Rth=3C/W
I <sub>VDD</sub>	VDD current capability	-	2	A	TW=1ms
I <sub>VSP</sub>	VSP input current	-	5	mA	
СОМ	Power Ground	VCC - 24	VCC + 0.3		
V <sub>HCOM</sub>	Hall Sensor input common mode voltage	-0.3	VDD		
$V_{PG}$	Open drain output motor evolution pulse	-0.3	VCC+0.3		
$V_{VSP}$	Analog input voltage VSP	-0.3	10.0	V	
$V_{DIR}$ $V_{EFF}$	Direction, Efficiency curve pins input voltage	-0.3	VDD+0.3		
VDD	3.3V voltage regulator output	-0.3	3.6		No short to ground
PD	Package power dissipation @ Tc ≤ +100 °C <sup>1)</sup>	-	5	W	
TJ	Junction temperature <sup>1)</sup>	-	150		
TS	Storage temperature <sup>1)</sup>	-55	150	°C	
TL	Lead temperature (soldering, 10 seconds) <sup>1)</sup>	-	260		

<sup>1)</sup> Guarantee by design, not tested at manufacturing

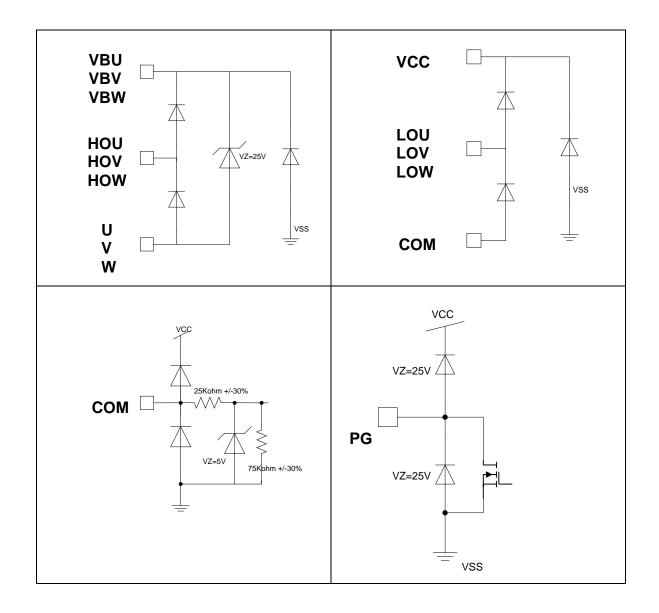
<sup>2)</sup> Output capacitance between VB-VS and VS-COM are same within +/-1%



### ESD structure









### **Recommended Operating Conditions**

For proper operation, the device should be used within the recommended conditions. All voltage parameters are absolute voltages referenced to **VSS** unless otherwise stated in the table.

The input/output logic timing diagram is shown in Fig. 1.

The VS and VSS offset rating are tested with all supplies biased at a 15 V (VCC) differential / 3.3V (VDD).

Power up and down sequences are not dependent on the order of VCC, DCBUS, and VSP for proper operation to start or stop.

Symbol	Definition	Min.	Тур	Max.	Units	Condition
$V_U, V_V, V_W$	PWM output motor voltage <sup>1)</sup>	100	320	450	V	IRDM982-025MB IRDM982-035MB
V <sub>PWMTR</sub>	Transient PWM output	-50	0	500		50ns transient period
V PWMTR	motor voltage †1)	-50	0	250		Sons transient period
D.	Q (a) (a) (a) (b) (a) (b) (a) (a) (b) (a) (b) (a) (b) (a) (b) (b) (b) (b) (b) (b) (b) (b) (b) (b	-	50	-	10/	Fc=20kHz, DCBUS=300V, IO=140mArms, no heatsink, Ta=40C, IRDM982-025MB
Po	Output power <sup>1)</sup>	-	60	-	W	Fc=20kHz, DCBUS=300V, IO=200mArms, no heatsink, Ta=40C, IRDM982-035MB
VCC	Low side supply voltage	13.5 <sup>1)</sup>	15	16.5 <sup>1)</sup>		
$V_{COM}$	COM-VSS voltage	-5	0	5		
V <sub>HCOM</sub>	Hall sensor input voltage COMMON MODE	0.6	-	2.9		
$V_{\text{DIR}},V_{\text{EFF}}$	Direction, Efficiency curve selection input pin voltage	0	-	VDD	V	
$V_{PG}$	Open drain output motor evolution pulse	0	-	VCC	v	
$V_{VSP}$	VSP input voltage	0	-	9.8		
VDD	3.3V voltage regulator output	3.0	-	3.6		lo=2mA
VDDstby	3.3V voltage regulator output when in stand by <sup>1)</sup>	0	-	0.8		VSP<1,15V for more than 5 s, Cout=20pF
$I_{VDD}$	VDD current capability	-	-	2	mA	TW=1ms
$C_{\text{VDD}}$	Capacitor at VDD	2.2	-	22	uF	
FCRmax	Carrier frequency	23.3k	23.9k	24.5k		$R_{CLKIN}$ =57.6K $\Omega$ , $C_{CLKIN}$ =270pF $F_{CLKIN}$ =38.99kHz
FCRtyp	Carrier frequency	18.1k	18.5k	18.9k	Hz	$R_{CLKIN}$ =75KΩ, $C_{CLKIN}$ =270pF $F_{CLKIN}$ =30.31kHz
FCRmin	Carrier frequency	14.5k	14.7k	15.0k		$R_{CLKIN}$ =95.3KΩ, $C_{CLKIN}$ =270pF $F_{CLKIN}$ =24.07kHz
R <sub>CLKIN</sub>	Resistor for RC oscillator <sup>2)</sup>	-	75K 39.2K	-	Ω	R=75kohm with C=270pF, C <sub>PCB</sub> =0pF Fc=18.83kHz R=75kohm with C=270pF, C <sub>PCB</sub> =5pF Fc=18.50kHz
C <sub>CLKIN</sub>	Capacitor for RC oscillator <sup>2)</sup>	-	270 470	-	pF	R=39.2kohm with C=470pF, C <sub>PCB</sub> =0pF Fc=20.75kHz R=39.2kohm with C=470pF, C <sub>PCB</sub> =5pF Fc=20.54kHz
TA	Ambient temperature <sup>1)</sup>	-40		125	°C	

†Operational for transient negative VS of - 50 V with a 50 ns pulse width is guaranteed by design. Refer to the Application Information section of this datasheet for more details.

- 1) Guarantee by design, not tested at manufacturing
- 2) Carrier Frequency is calculated by the following.  $FC=1/(((R+50)\times (C+5\times 10^{\cdot12}+C_{PCB})+900\times 10^{\cdot9})\times 2.466)$   $C_{PCB}: Board layout capacitance$

*i*MOTION™



#### Static Electrical Characteristics

 $(V_{\text{CC}}\text{-COM}) = (V_{\text{B}}\text{-}V_{\text{S}}) = 15 \text{ V}$ . TA = 25°C unless otherwise specified. The VSP and IIN parameters are referenced to  $V_{\text{SS}}$  and are applicable to all six channels. The VO and IO parameters are referenced to respective  $V_{\text{S}}$  and COM and are applicable to the respective output leads HO or LO. The  $V_{\text{CCUV}}$  parameters are referenced to  $V_{\text{SS}}$ . The  $V_{\text{BSUV}}$  parameters are referenced to  $V_{\text{S}}$ .

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
	DC bus to COM leakage current, IRDM982-035MB	-	70	200	)	
IDSS	DC bus to COM leakage current, IRDM982-025MB	-	50	100	uA	
VF	MOSFET body diode voltage, IRDM982-025MB	-		1.0 <sup>2)</sup>		IF=1A
	MOSFET body diode voltage, IRDM982-035MB	-		1.0 <sup>2)</sup>		
VDD	VDD voltage	3.0	3.3	3.6		lo=2mA
VIH	Logic "1" input voltage	2.5	-	-		
VIL	Logic "0" input voltage	-	-	0.8		
VSPstbylow	Active to Standby mode VSP input negative going thresholds	1.05	1.15	1.25		
VSPstbyhigh	Standby to Active mode VSP input positive going thresholds	1.3	1.4	1.5	.,,	
VSPstbyhys	Standby mode VSP hysteresis	0.1	0.25	0.4	V	
VSPmin	VSP 0%duty	1.9	2.1	2.3		
VSPmax	VSP 100%duty	5.2	5.4	5.6		
VSP6step enter	VSP voltage that ensures enter in 6 step mode	8.0	8.8	9.68		500 ms continuously above threshold
VSP6step exit	VSP voltage that ensures exit from 6 step mode	8.0	8.8	9.68		200 ms continuously below threshold
V <sub>нсом</sub>	Hall sensor input voltage COMMON MODE	0.6	2	2.9		
V <sub>HDIF</sub>	Hall sensor input voltage DIFFERENTIAL MODE	0.03	0.5	2.5		
$V_{NOG}$	Hall sensor input OP amp open loop gain <sup>1)</sup>	60	-	80	dB	Ta=-40 - 125C
V <sub>HOO</sub>	Hall sensor input OP amp offset1)	-	1	-	mV	
V <sub>IHSTH</sub>	Hall sensor input Schmitt Trigger input buffer hysteresis <sup>1)</sup>	ı	1	-		
V <sub>HST+</sub>	Hall sensor input Digital Schmitt Trigger input buffer positive going voltage <sup>1)</sup>	i	2	-		
V <sub>HST-</sub>	Hall sensor input Digital Schmitt Trigger input buffer negative going voltage <sup>1)</sup>	-	1	-		
V <sub>CLKIN,TH+</sub>	CLKIN positive going threshold	2.5	-	-		
V <sub>CLKIN,TH-</sub>	CLKIN negative going threshold	-	-	0.8	V	
V <sub>CC,UVTH+</sub>	$V_{\text{CC}}$ supply undervoltage positive going Threshold	8	8.9	9.8		
V <sub>CC,UVTH-</sub>	$V_{CC}$ supply undervoltage negative going Threshold	7.4	8.2	9		
V <sub>CC,UVHYS</sub>	V <sub>CC</sub> supply undervoltage hysteresis	0.3	0.7	-		
V <sub>BS,UVTH+</sub>	V <sub>BS</sub> supply undervoltage positive going Threshold	8	8.9	9.8		
V <sub>BS, UVTH</sub> -	$V_{\mbox{\footnotesize{BS}}}$ supply undervoltage negative going Threshold	7.4	8.2	9	V	
$V_{BS,UVHYS}$	V <sub>BS</sub> supply undervoltage hysteresis	0.3	0.7	-		
V <sub>ILIM1</sub>	Current Limit Input voltage 1 3)	450	520	590		Tc<116C
V <sub>ILIM2</sub>	Current Limit Input voltage 2 3)	300	375	450	mV	Tc=116<132C
V <sub>ILIM3</sub>	Current Limit Input voltage 3 3)	200	250	300		Tc=132-<140C



Current Limit input voltage at Rotor Lock	200	250	300			
Current Limit Input voltage hysteresis	-	60	-			
Positive going overtemperature limit	130	140	150	°C		
Negative going overtemperature limit	95	105	115			
Temp sensor absolute accuracy	0	-	12			
Temp sensor resolution <sup>1)</sup>	0	-	3.25			
Vcc current	-	13	24	mA		
Vcc current at standby	-	0.10	0.20			
3.3V output current	-	-	2			
External capacitor for VDD <sup>1)</sup>	2.2	-	22	uF		
PWM pulse width resolution	-	500	-	Counts	100ns resolution	
Internal modulator amplitude resolution <sup>1)</sup>	-	1686	-			
PWM carrier frequency	19.6	20	20.4	kHz	CLKIN=32.768kHz	
XTAL pin frequency <sup>1)</sup>	29.6	30.3	30.9		R=75kohm, C=270pF	
	32.2	32.8	33.5		R=40.2kohm, C=470pF	
Ron internal bootstrap diode	-	220	-	Ω		
Standby power dissipation	-	1.5	3.0	mW	VSP<1.15V, DCBUS=0V	
Internal driver gate drive sourcing current <sup>1)</sup>		6			V <sub>DRV</sub> =0 V,PW ≤10 μs	
Internal driver gate drive sinking current <sup>1)</sup>	-	160	-	mA	V <sub>DRV</sub> =15 V, PW ≤10 μs	
Ron of SPDFBK pin	-	50	100	Ω	Ω	
Thermal resistance, junction to case <sup>1)</sup>	-	3	-	°C W	IRDM982-025MB	
memanesistance, junction to case	-	2	-	] 0,,,,	IRDM982-035MB	
	Current Limit Input voltage hysteresis  Positive going overtemperature limit  Negative going overtemperature limit  Temp sensor absolute accuracy  Temp sensor resolution¹¹  Vcc current  Vcc current at standby  3.3V output current  External capacitor for VDD¹¹  PWM pulse width resolution  Internal modulator amplitude resolution¹¹  PWM carrier frequency  XTAL pin frequency¹¹)  Ron internal bootstrap diode  Standby power dissipation  Internal driver gate drive sourcing current¹¹  Internal driver gate drive sinking current¹¹	Current Limit Input voltage hysteresis  Positive going overtemperature limit  130  Negative going overtemperature limit  75  Temp sensor absolute accuracy  Temp sensor resolution 1)  Vcc current  Vcc current	Current Limit Input voltage hysteresis  Positive going overtemperature limit  Negative going overtemperature limit  Temp sensor absolute accuracy  Temp sensor resolution¹)  Vcc current	Current Limit Input voltage hysteresis         -         60         -           Positive going overtemperature limit         130         140         150           Negative going overtemperature limit         95         105         115           Temp sensor absolute accuracy         0         -         12           Temp sensor resolution <sup>1)</sup> 0         -         3.25           Vcc current         -         13         24           Vcc current at standby         -         0.10         0.20           3.3V output current         -         -         2           External capacitor for VDD <sup>1)</sup> 2.2         -         22           PWM pulse width resolution         -         500         -           Internal modulator amplitude resolution <sup>1)</sup> -         1686         -           PWM carrier frequency         19.6         20         20.4           XTAL pin frequency <sup>1)</sup> 29.6         30.3         30.9           32.2         32.8         33.5           Ron internal bootstrap diode         -         220         -           Standby power dissipation         -         1.5         3.0           Internal driver gate drive sourcing current <sup>1)</sup> <	Current Limit Input voltage hysteresis         -         60         -           Positive going overtemperature limit         130         140         150           Negative going overtemperature limit         95         105         115           Temp sensor absolute accuracy         0         -         12           Temp sensor resolution¹¹)         0         -         3.25           Vcc current         -         13         24         mA           Vcc current at standby         -         0.10         0.20           3.3V output current         -         -         2           External capacitor for VDD¹¹         2.2         -         22         uF           PWM pulse width resolution         -         500         -         Counts           Internal modulator amplitude resolution¹¹         -         1686         -           PWM carrier frequency         19.6         20         20.4         kHz           XTAL pin frequency¹¹)         29.6         30.3         30.9           32.2         32.8         33.5           Ron internal bootstrap diode         -         220         -         Ω           Standby power dissipation         -         1.5         3.0	

<sup>1)</sup> Guaranteed by design, not tested at manufacturing

<sup>2)</sup> Tested at wafer probe

<sup>3)</sup> V<sub>ILIM1,2,3</sub> thresholds are tested at 25 degC. Temperature range is based on characterization only.



### **Dynamic Electrical Characteristics**

 $V_{CC}$ =  $V_B$  = 15 V,  $V_S$  =  $V_{SS}$  = COM,  $T_A$  = 25°C, and  $C_L$  = 1000 pF unless otherwise specified.

Symbol	Definition	Min	Тур	Max	Units	Test Conditions
	Short Circuit Drain Current <sup>1)</sup>	-	3	-	Α	$IRDM982-025MB, T_J=25^{\circ}C, t_{SC}<20\mu s$ $V^{+}=320V, V_{CC}=15V$
Icsc	Short Great Drain Gurient	-	5	-	Α	IRDM982-035MB, $T_J$ =25°C, $t_{SC}$ <20 $\mu$ s $V^+$ = 320V, $V_{CC}$ =15V
SCSOA	Short Circuit duration period <sup>1)</sup>	20000	-	-	ns	$V^+$ = 300V(IRDM982-025MB,- 35MB), $V_{CC}$ =+15V to 0V, line to line short
t <sub>RR</sub>	Reverse recovery time 1)	-	80	-	ns	ID=1A, di/dt=100A/us
t <sub>iLIM</sub>	ILIM to PWM current limit propagation delay	-	3000	-	ns	$C_{LOAD} = 1nF, F_{CLKIN} = 32.768kHz$
		500	1000	1700		VILIM=2V, Ta=25C
t <sub>ILIMFIL</sub>	ILIM filter time <sup>1)</sup>	400	800	1400		VILIM=2V, Ta=125C
		600	1200	2000	ns	VILIM=2V, Ta=-40C
t <sub>HFILA</sub>	Hall differential input analog filter1)	-	1500	-	110	
t <sub>HFILD</sub>	Hall input digital filter delay <sup>1)</sup>	-	2500	-		F <sub>CLKIN</sub> =32.768kHz
t <sub>HALLSAT</sub>	HALL input response time from saturation <sup>1)</sup>	-	5000	-		
t <sub>HALLPG</sub>	HALL input to PG output propagation delay	-	5000	-		F <sub>CLKIN</sub> =32.768kHz
t <sub>vspact</sub>	VSP standby to PWM active time	14.0	17.5	22.0	ms	CVDD=2.2uF, VSP=0→5.4V, F <sub>CLKIN</sub> =32.768kHz
T <sub>VSPONDELAY</sub>	VSP active to PWM duty active	2.0	3.5	5.0		VSP from 1.8V to 2.6V, F <sub>CLKIN</sub> =32.768kHz
t <sub>VDDHOLD</sub>	VDD hold time at standby <sup>1)</sup>	4.9	5.0	5.1	S	CVDD=2.2uF, VSP=2→0V, F <sub>CLKIN</sub> =32.768kHz
t <sub>RLOCKDETECT</sub>	Rotor Lock detect time <sup>1)</sup>	4.9	5	5.1	0	VSP>2.1V,  Elec freq <3Hz, F <sub>CLKIN</sub> =32.768kHz
DT	Deadtime	-	1000	-		F <sub>CLKIN</sub> =32.768kHz
PW <sub>HIN</sub>	Internal high side minimum pulse width	-	400	-	ns	Not a final output of a part , F <sub>CLKIN</sub> =32.768kHz
$PW_{LIN}$	Internal low side minimum pulse width	-	100	-		Not a final output of a part , F <sub>CLKIN</sub> =32.768kHz
SPD <sub>OVER</sub>	Over speed <sup>1)</sup>	-	200	-		F <sub>CLKIN</sub> =32.768kHz
SPD <sub>PWMCHG</sub>	Block commutation to sine PWM change speed <sup>1)</sup>	-	3	-	Hz	1 consecutive electrical angle update period, F <sub>CLKIN</sub> =32.768kHz
SPD <sub>EFF1</sub>	EFF bending point 1 speed <sup>1)</sup>	-	33.33	-		F <sub>CLKIN</sub> =32.768kHz
SPD <sub>EFF2</sub>	EFF bending point 2 speed <sup>1)</sup>	-	83.33	-		F <sub>CLKIN</sub> =32.768kHz

<sup>1)</sup> Guaranteed by design, not tested at manufacturing



## Figures of Input Circuit and Table

The following Figure shows the interconnect bonding among the HVIC and MOSFETs within a package.

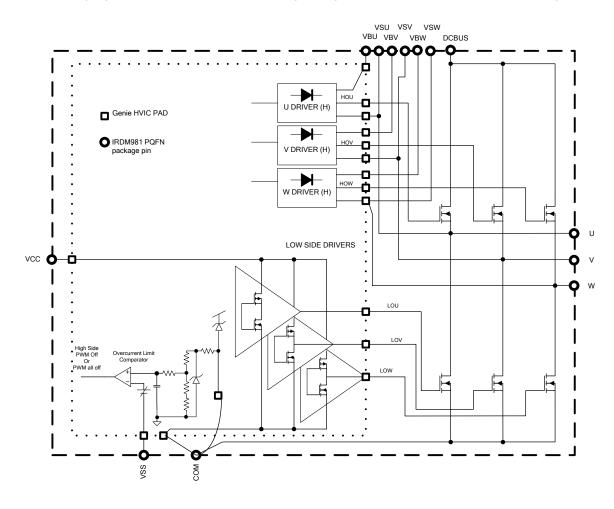


Figure 11 Connection diagram of VSS/COM and power pins/pads



The following Figures show the VSP input mapping, the Hall sensor input circuit, and the ISENSE pin input filter circuit.

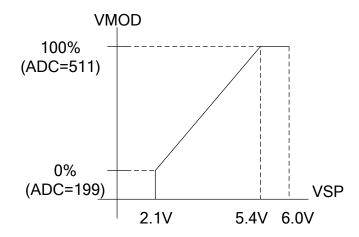


Figure 12 VSP Range and Thresholds

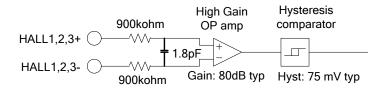


Figure 13 Hall sensor input circuit

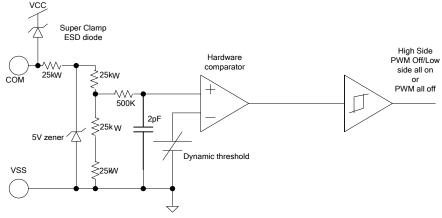


Figure 14 COM pin current limit comparator and analog filter



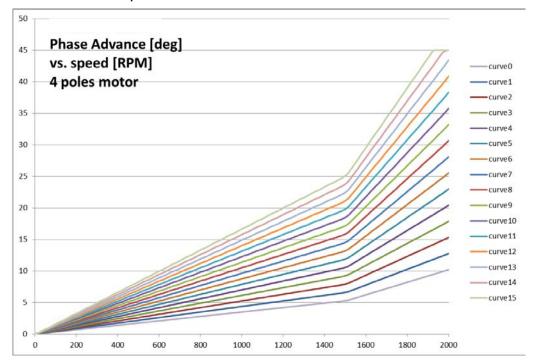
## **Load Curves**

The following Table shows EFF pin mapping between input voltage and the advanced angle in degree per 50Hz of fundamental electrical frequency. Phase advance is by design clamped to be lower than 45 degrees at every frequency. At frequencies above 100 Hz the advancement is constant and it is kept to the same value at 100Hz.

Select	Degree/50Hz	Frequency [Hz] @ advance=45deg	EFF input	EFF digital input
15	25.49	64.22	3.094V - 3.300V	152
14	24.15	65.75	2.888V - 3.087V	144
13	22.81	68.04	2.681V - 2.881V	136
12	21.47	70.34	2.475V - 2.675V	128
11	20.12	72.63	2.269V - 2.469V	120
10	18.78	75.69	2.063V - 2.262V	112
9	17.44	78.75	1.856V - 2.056V	104
8	16.10	81.80	1.650V - 1.850V	96
7	14.76	87.16	1.444V - 1.644V	88
6	13.42	92.51	1.238V - 1.437V	80
5	12.07	99.39	1.031V - 1.231V	72
4	10.73	Advance=40deg above 100Hz	0.825V - 1.025V	64
3	9.39	Advance=35deg above 100Hz	0.619V - 0.819V	56
2	8.05	Advance=30deg above 100Hz	0.413V - 0.612V	48
1	6.71	Advance=25deg above 100Hz	0.206V - 0.406V	40
Default = 0	5.37	Advance=20deg above 100Hz	0.000V - 0.200V	32

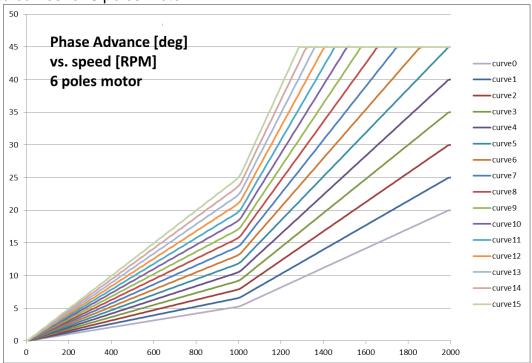
Table 2a EFF Parameters Selection

### Load curves for 4 poles motor

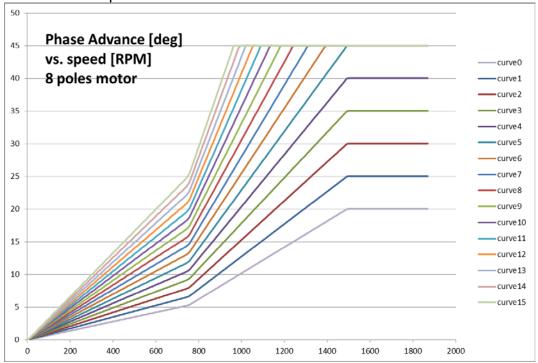








## Load curves for 8 poles motor



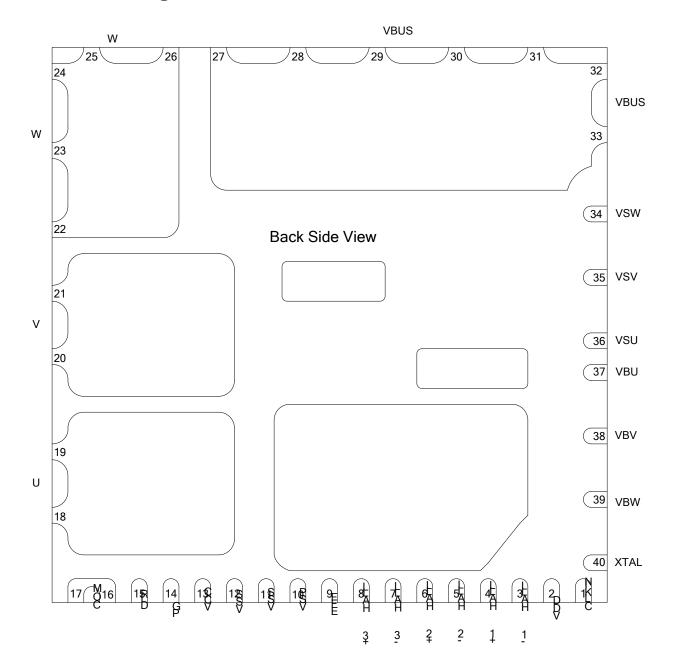


# **Lead Definitions**

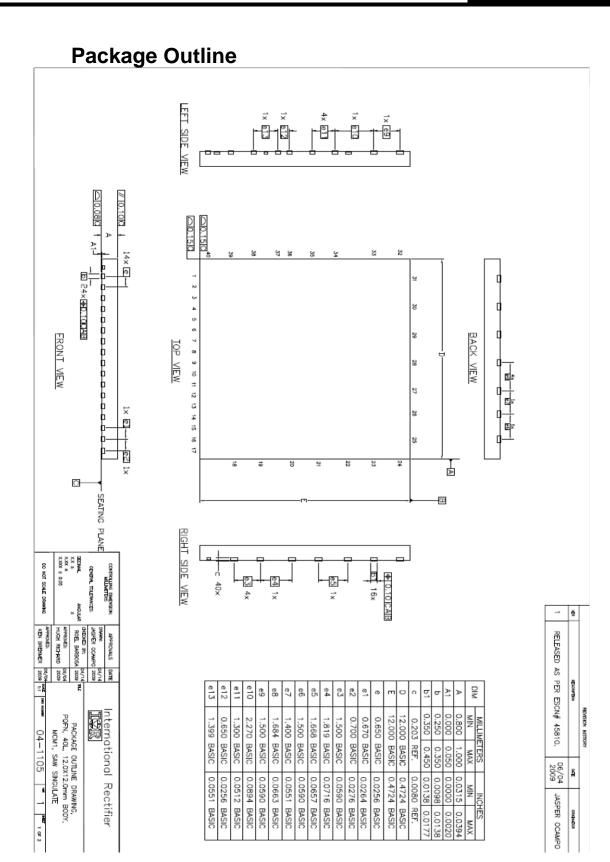
Symbol	Pin#	Description
VSP	10	Voltage Set Point analog input. Provides the value of the PWM modulation index to the controller.
PG	14	Provides speed feedback to through pulses per revolution. It is an open drain output 15V tolerant. Output is a square wave of a 3 pulses per electrical cycle of fundamental frequency
DIR	15	Motor Direction Input (internally pulled up high = U→V→W)
EFF	9	Load curve selection parameter Input for efficiency improvement
XTAL	40	Clock buffer output
CLKIN	1	Clock buffer input
VSS	11	Logic ground
СОМ	16,17	Analog input ITRIP and Power Ground and Low side MOSFET cource
vcc	13	15V supply voltage
HALL1+	4	Hall sensor 1 positive input
HALL1-	3	Hall sensor 1 negative input
HALL2+	6	Hall sensor 2 positive input
HALL2-	5	Hall sensor 2 negative input
HALL3+	8	Hall sensor 3 positive input
HALL3-	7	Hall sensor 3 negative input
VDD	2	3.3V output
U	18,19	U phase output
٧	20,21	V phase output
w	22,23,24, 25,26	W phase output
VBU	37	Phase U High side Bootstrap capacitor positive
VBV	38	Phase V High side Bootstrap capacitor positive
VBW	39	Phase W High side Bootstrap capacitor positive
VSU	36	Phase U High side Bootstrap capacitor negative
VSV	35	Phase V High side Bootstrap capacitor negative
vsw	34	Phase W High side Bootstrap capacitor negative
DCBUS	27,28,29, 30,31,32, 33	DC Bus voltage



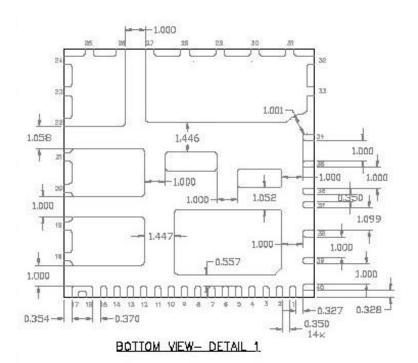
# **Lead Assignments**

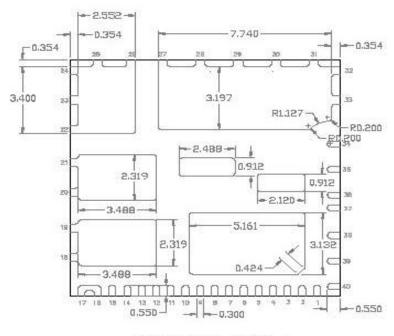










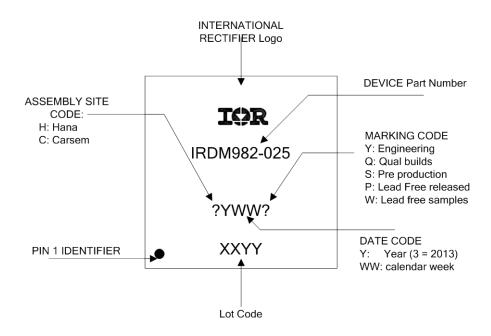


BOTTOM VIEW- DETAIL 2

Dimension in mm<sup>2</sup>



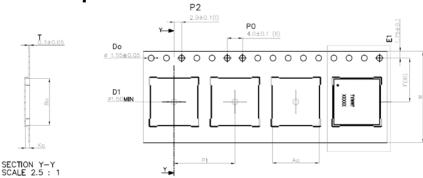
# **Package Marking**



Part number	Internal MOSFET
IRDM982-025MB	500V 2A
IRDM982-035MB	500V 3A



## **Tape and Reel Details**

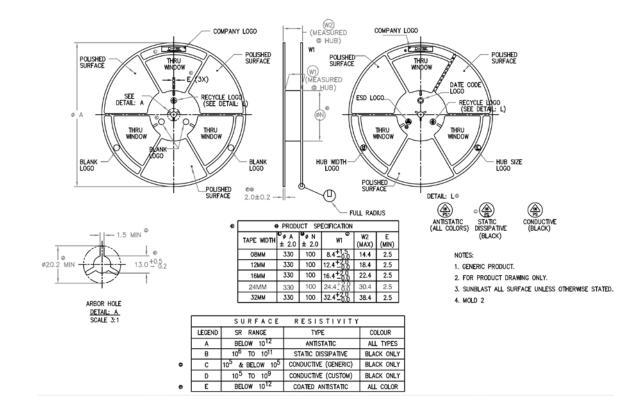


Ao	12.3 +/- 0.1
Во	12.3 +/- 0.1
Ko	1.10 +/- 0.1
F	11.50 +/- 0.1
P1	16.00 +/- 0.1
W	24.00 +/- 0.3

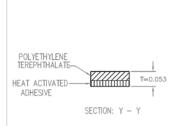
- Measured from centerline of sprocket hole to centerline of pocket.
- (II) Cumulative tolerance of 10 sprocket holes is  $\pm$  0.20 .
- (III) Measured from centerline of sprocket hole to centerline of pocket.
- (IV) Other material available.

ALL DIMENSIONS IN MILLIMETERS UNLESS OTHERWISE STATED.



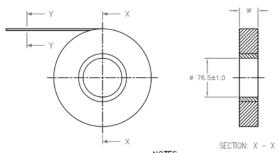






#### TABLE 2:

STANDARD COVER TAPE WIDTH (W ± 0.1)	CARRIER TAPE WIDTH
5.3, 5.4	8
9.2, 9.3	12
13.3	16
21.0, 21.3	24
25.5	32
37.5	44
49.5	56



NOTES:

- 1. THICKNESS: 0.048-0.058 mm.
- 2. STANDARD LENGTH: 300 m
- 3. TENSILE STRENGTH: 7.7 kg/mm sq.
- 4. ELONGATION: 120%
- 5. SURFACE RESISTIVITY: 10 ohms/SQ. MAX (STATIC DISSIPATIVE)
- 6. PEEL STRENGTH CONFORMS TO EIA SPEC.  $55\pm25g$
- 7. LUMINOUS TRANSMITTANCE: 91%
- 8. HAZE: 50%
- 9. OTHER COVER TAPE WIDTH REFER TO W14.08-04

ALL DIMENSIONS IN MILLIMETERS UNLESS OTHERWISE STATED.



# Soldering temperature profile

The following soldering temperature profile is recommended. Any temperature which may exceed those indicated below is not recommended and may cause a permanent damage to the physical component such as deformation.

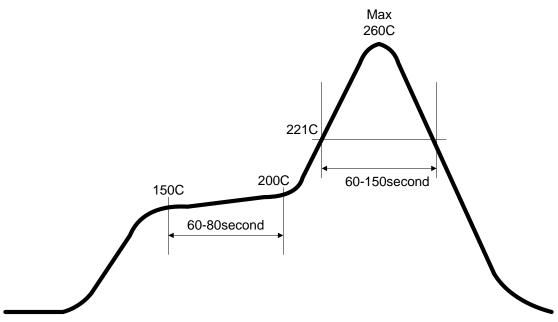


Figure 13 Recommended soldering temperature profile

Condition	Value	Remark
Temperature rise rate	3°C	
Temperature fall rate	6°C	
Number of reflow	2	
Manual soldering temperature	260°C	
Manual soldering time	10 second	

Table 3 Recommended soldering reflow condition

#### Trademarks of Infineon Technologies AG

HIVIC™, µIPM™, µPFC™, AU-ConvertIR™, AURIX™, C166™, CanPAK™, CIPOS™, CIPURSE™, CoolDP™, CoolGan™, COOLIR™, CoolMOS™, CoolSiC™, DAVE™, DI-POL™, DirectFET™, DrBlade™, EasyPIM™, EconoBRIDGE™, EconoDUAL™, EconoPACK™, EconoPIM™, EiceDRIVER™, eupec™, FCOS™, GanpowiR™, HEXFET™, HITFET™, HybridPACK™, iMOTION™, IRAM™, ISOFACE™, IsoPACK™, LEDrivIR™, LITIX™, MIPAQ™, ModSTACK™, my-d™, NovalithiC™, OPTIGA™, OptiMOS™, ORIGA™, PowIRaudio™, PowIRStage™, PrimePACK™, PrimeSTACK™, PROFET™, PRO-SIL™, RASIC™, REAL3™, SmartLEWIS™, SOLID FLASH™, SPOC™, StrongIRFET™, SupIRBuck™, TEMPFET™, TRENCHSTOP™, TriCore™, UHVIC™, XHP™, XMC™

Trademarks updated November 2015

#### Other Trademarks

Edition 2015-04-08

Published by Infineon Technologies AG 81726 München, Germany

© 2016 Infineon Technologies AG. All Rights Reserved.

Do you have a question about this document?

Email: erratum@infineon.com

Document reference

#### IMPORTANT NOTICE

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to suc

Downloaded From Oneyac.com

For further information on the product, technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies office (www.infineon.com).

#### WARNINGS

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

单击下面可查看定价,库存,交付和生命周期等信息

>>Infineon Technologies(英飞凌)